BAT54CXV3T1

Preferred Device

Dual Series Schottky Barrier Diodes

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Low Forward Voltage 0.35 V (Typ) @ $I_F = 10 \text{ mAdc}$
- Pb–Free Package is Available

Rating

Reverse Voltage

Forward Power Dissipation

@ $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$

Storage Temperature Range

Junction-to-Ambient (Note 1)

1. FR-5 board with minimum mounting pad.

Forward Current (DC)

Junction Temperature

Thermal Resistance,

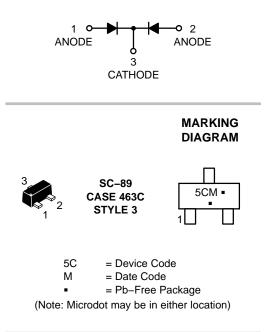
reliability may be affected.



ON Semiconductor®

http://onsemi.com

30 VOLT DUAL COMMON CATHODE SCHOTTKY BARRIER DIODES



MAXIMUM RATINGS (T_{.1} = 125°C unless otherwise noted)

Symbol

 V_{R}

 P_{F}

 I_{F}

ТJ

T_{sta}

 $R_{\theta JA}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not

normal operating conditions) and are not valid simultaneously. If these limits are

exceeded, device functional operation is not implied, damage may occur and

Value

30

240

1.9

200 Max

-55 to 125

-55 to +150

525

Unit

V

mW

mW/°C

mΑ

°C

°C

°C/W

ORDERING INFORMATION

Device	Package	Shipping [†]
BAT54CXV3T1	SC-89	3000 / Tape & Reel
BAT54CXV3T1G	SC-89 (Pb-Free)	3000 / Tape & Reel

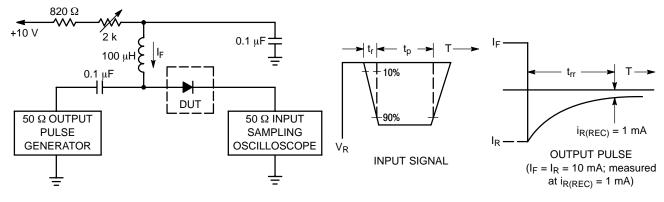
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

BAT54CXV3T1

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage $(I_R = 10 \ \mu A)$	V _{(BR)R}	30	_	_	V
Total Capacitance ($V_R = 1.0 V, f = 1.0 MHz$)	CT	-	7.6	10	pF
Reverse Leakage (V _R = 25 V)	I _R	-	0.5	2.0	μAdc
Forward Voltage (I _F = 0.1 mAdc)	V _F	-	0.22	0.24	Vdc
Forward Voltage (I _F = 30 mAdc)	V _F	-	0.41	0.5	Vdc
Forward Voltage (I _F = 100 mAdc)	V _F	-	0.52	0.8	Vdc
Reverse Recovery Time ($I_F = I_R = 10 \text{ mAdc}, I_{R(REC)} = 1.0 \text{ mAdc}, Figure 1$)	t _{rr}	-	-	5.0	ns
Forward Voltage (I _F = 1.0 mAdc)	V _F	-	0.29	0.32	Vdc
Forward Voltage (I _F = 10 mAdc)	V _F	-	0.35	0.40	Vdc
Forward Current (DC)	١ _F	-	-	200	mAdc
Repetitive Peak Forward Current	I _{FRM}	-	-	300	mAdc
Non-Repetitive Peak Forward Current (t < 1.0 s)	I _{FSM}	-	-	600	mAdc

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (EACH DIODE)



Notes: 1. A 2.0 k Ω variable resistor adjusted for a Forward Current (I_F) of 10 mA. 2. Input pulse is adjusted so I_{R(peak)} is equal to 10 mA. 3. t_p » t_{rr}

Figure 1. Recovery Time Equivalent Test Circuit

BAT54CXV3T1

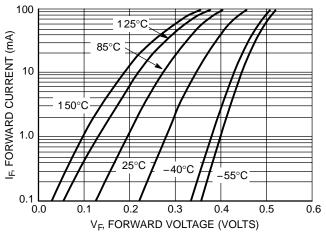


Figure 2. Forward Voltage

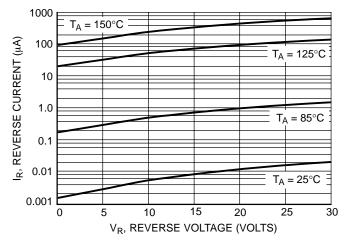


Figure 3. Leakage Current

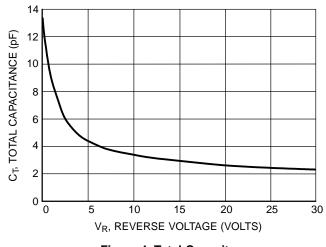
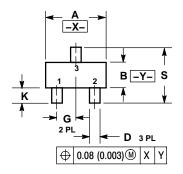


Figure 4. Total Capacitance

PACKAGE DIMENSIONS

SC-89, 3-LEAD CASE 463C-03 **ISSUE C**

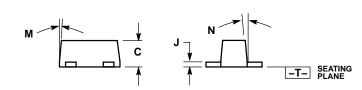


- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETERS 2
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS 3. IS THE MINIMUM THICKNESS OF BASE MATERIAL
- 4. 463C-01 OBSOLETE, NEW STANDARD 463C-02.

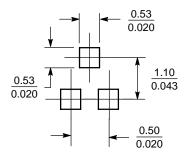
				-			
	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	1.50	1.60	1.70	0.059	0.063	0.067	
В	0.75	0.85	0.95	0.030	0.034	0.040	
С	0.60	0.70	0.80	0.024	0.028	0.031	
D	0.23	0.28	0.33	0.009	0.011	0.013	
G	C	.50 BSC)	0.020 BSC			
н	0.53 REF			0.021 REF			
J	0.10	0.15	0.20	0.004	0.006	0.008	
κ	0.30	0.40	0.50	0.012	0.016	0.020	
L	1.10 REF			0.043 REF			
М			10			10	
Ν			10			10	
S	1.50	1.60	1.70	0.059	0.063	0.067	

STYLE 3: PIN 1. ANODE 2. ANODE

3. CATHODE



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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